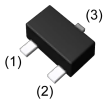
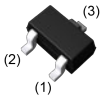
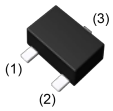
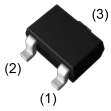
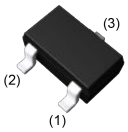
DTA114E series

PNP -100mA -50V Digital Transistors (Bias Resistor Built-in Transistors) Datasheet

Parameter	Value
V_{CC}	-50V
$I_{C(MAX.)}$	-100mA
R_1	10kΩ
R_2	10kΩ

●Outline

VMT3  DTA114EM (SC-105AA)	EMT3F  DTA114EEB (SC-89)
EMT3  DTA114EE SOT-416(SC-75A)	UMT3F  DTA114EUB (SC-85)
UMT3  DTA114EUA SOT-323(SC-70)	SMT3  DTA114EKA SOT-346(SC-59)

●Features

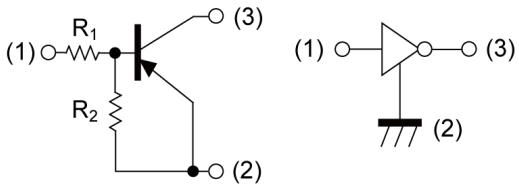
1) Built-In Biasing Resistors, $R_1 = R_2 = 10kΩ$
2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit) .
3) Only the on/off conditions need to be set for operation, making the circuit design easy.
4) Complementary NPN Types: DTC114E series

●Application

INVERTER, INTERFACE, DRIVER

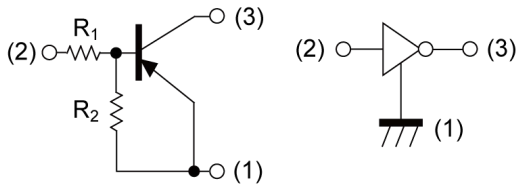
●Inner circuit

DTA114EM/ DTA114EEB/ DTA114EUB



(1) IN (BASE)
(2) GND (+) (EMITTER)
(3) OUT (COLLECTOR)

DTA114EE/ DTA114EUA/ DTA114EKA



(1) GND (+) (EMITTER)
(2) IN (BASE)
(3) OUT (COLLECTOR)

●Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
DTA114EM	VMT3	1212	T2L	180	8	8000	14
DTA114EEB	EMT3F	1616	TL	180	8	3000	14
DTA114EE	EMT3	1616	TL	180	8	3000	14
DTA114EUB	UMT3F	2021	TL	180	8	3000	14
DTA114EUA	UMT3	2021	T106	180	8	3000	14
DTA114EKA	SMT3	2928	T146	180	8	3000	14

●Absolute maximum ratings (T_a = 25°C)

Parameter		Symbol	Values	Unit
Supply voltage		V_{CC}	-50	V
Input voltage		V_{IN}	-40 to 10	V
Output current		I_O	-50	mA
Collector current		$I_{C(MAX)}$ *1	-100	mA
Power dissipation	DTA114EM	P_D *2	150	mW
	DTA114EEB		150	
	DTA114EE		150	
	DTA114EUB		200	
	DTA114EUA		200	
	DTA114EKA		200	
Junction temperature		T_j	150	℃
Range of storage temperature		T_{stg}	-55 to +150	℃

●Electrical characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input voltage	$V_{I(off)}$	V_{CC} = -5V, I_O = -100μA	-	-	-0.5	V
	$V_{I(on)}$	V_O = -0.3V, I_O = -10mA	-3.0	-	-	
Output voltage	$V_{O(on)}$	I_O / I_I = -10mA / -0.5mA	-	-100	-300	mV
Input current	I_I	V_I = -5V	-	-	-880	μA
Output current	$I_{O(off)}$	V_{CC} = -50V, V_I = 0V	-	-	-500	nA
DC current gain	G_I	V_O = -5V, I_O = -5mA	30	-	-	-
Input resistance	R_1	-	7	10	13	kΩ
Resistance ratio	R_2/R_1	-	0.8	1.0	1.2	-
Transition frequency	f_T *1	V_{CE} = -10V, I_E = 5mA, f = 100MHz	-	250	-	MHz

*1 Characteristics of built-in transistor

*2 Each terminal mounted on a reference land

●Electrical characteristic curves (T_a =25°C)

Fig.1 Input voltage vs. output current (ON characteristics)

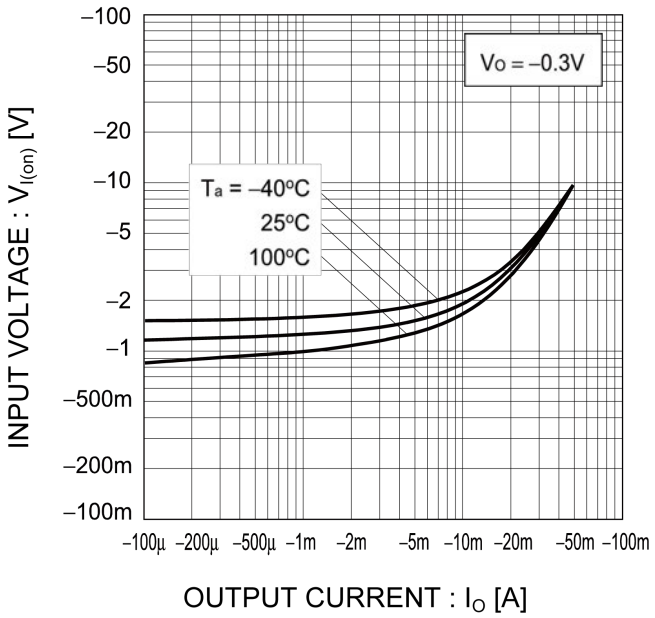


Fig.2 Output current vs. input voltage (OFF characteristics)

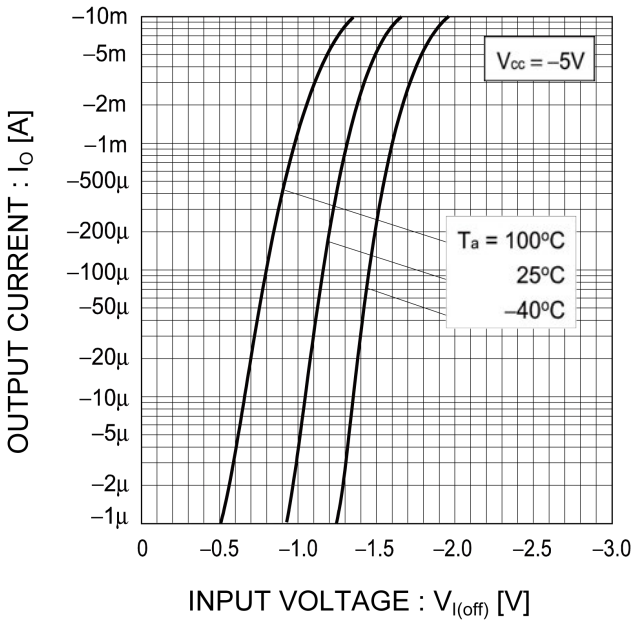


Fig.3 Output current vs. output voltage

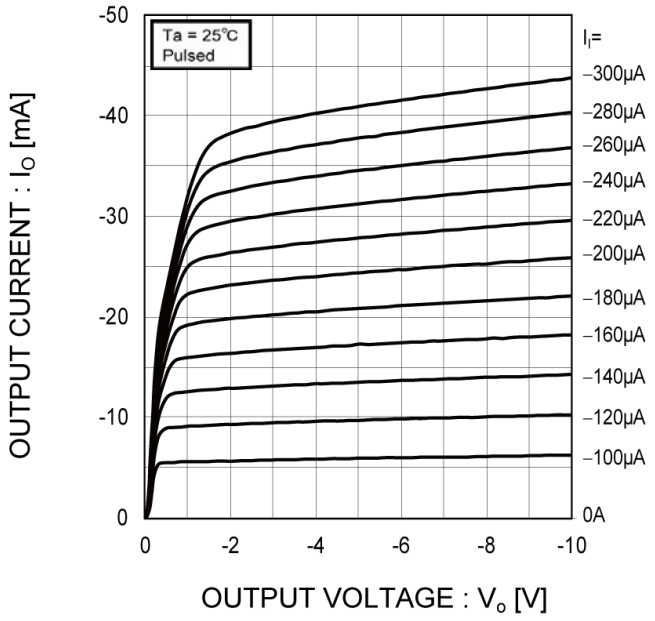
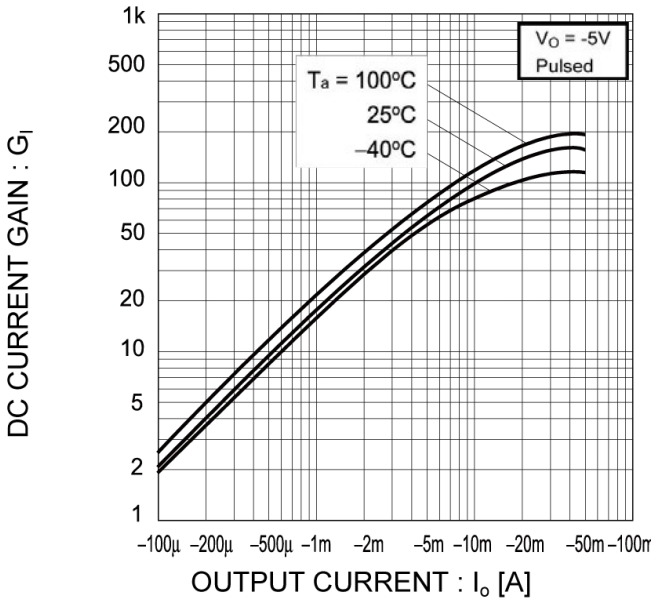
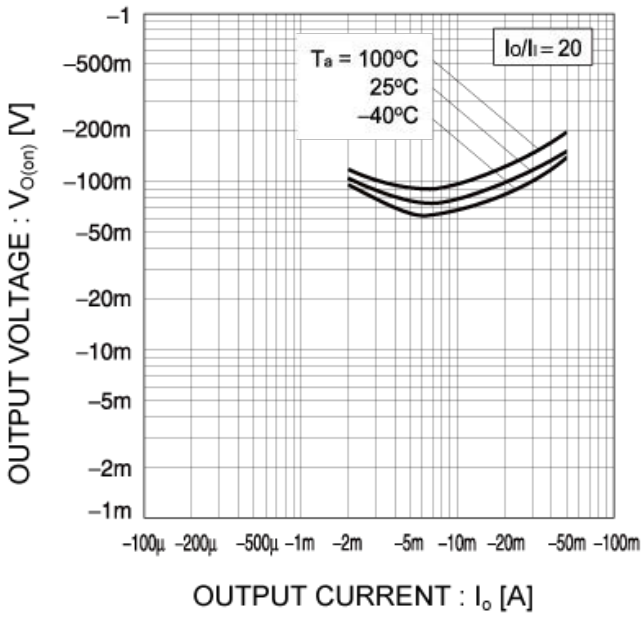


Fig.4 DC current gain vs. output current



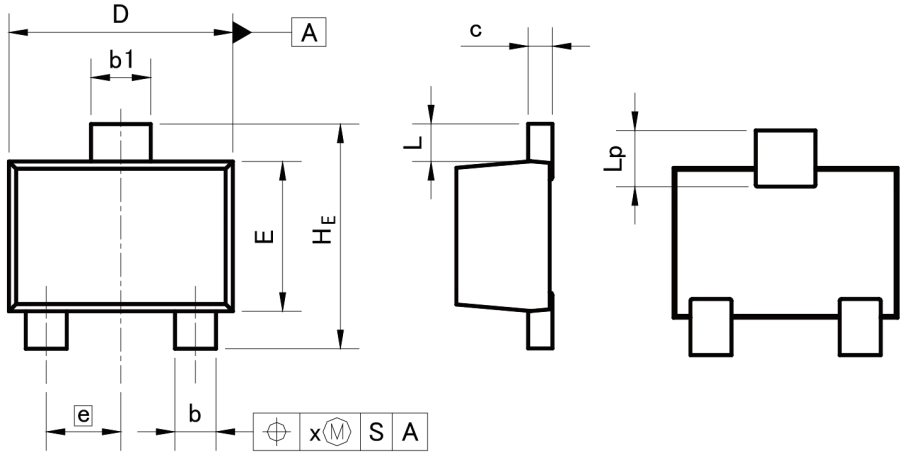
●Electrical characteristic curves (T_a =25°C)

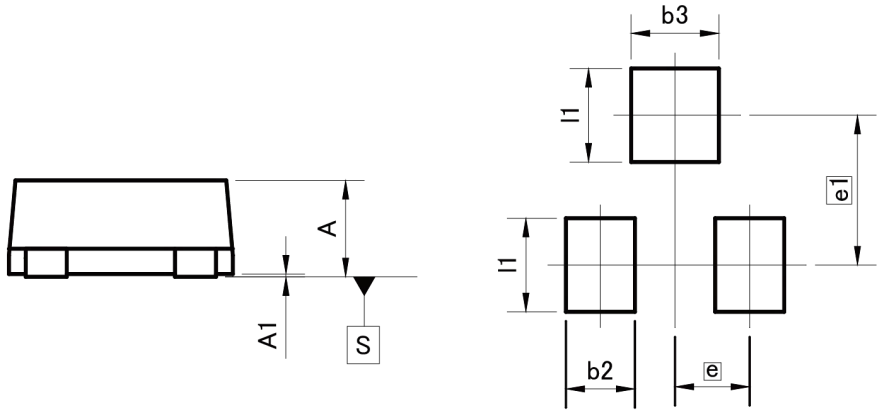
Fig.5 Output voltage vs. output current



●Dimensions

VMT3





Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

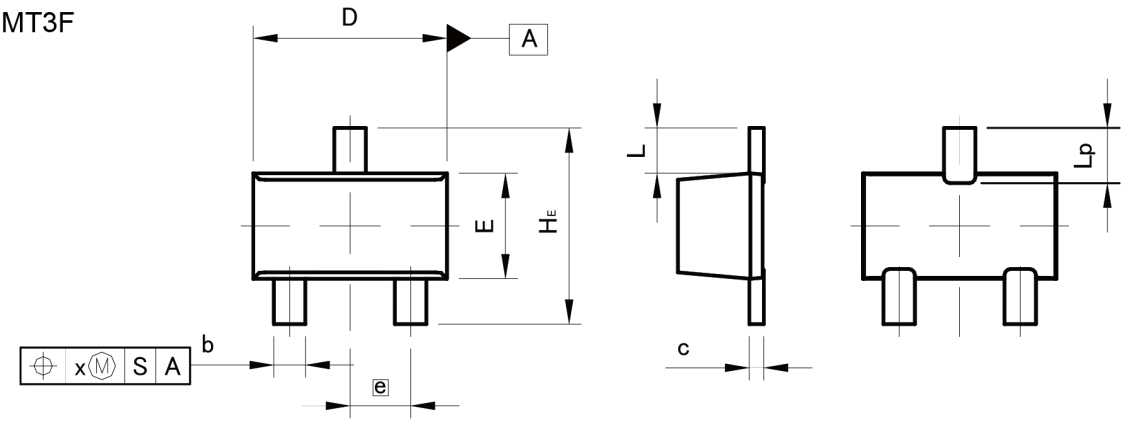
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.45	0.55	0.018	0.022
A1	0.00	0.10	0.000	0.004
b	0.17	0.27	0.007	0.011
b1	0.27	0.37	0.011	0.015
c	0.08	0.18	0.003	0.007
D	1.10	1.30	0.043	0.051
E	0.70	0.90	0.028	0.035
e	0.40		0.02	
HE	1.10	1.30	0.043	0.051
L	0.10	0.30	0.004	0.012
Lp	0.20	0.40	0.008	0.016
x	−	0.10	−	0.004

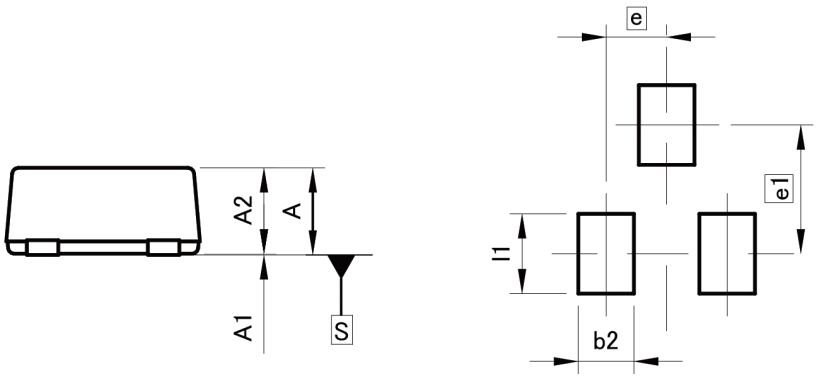
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	−	0.37	−	0.015
b3	−	0.47	−	0.019
e1	0.80		0.031	
l1	−	0.50	−	0.020

Dimension in mm/inches

●Dimensions

EMT3F





Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

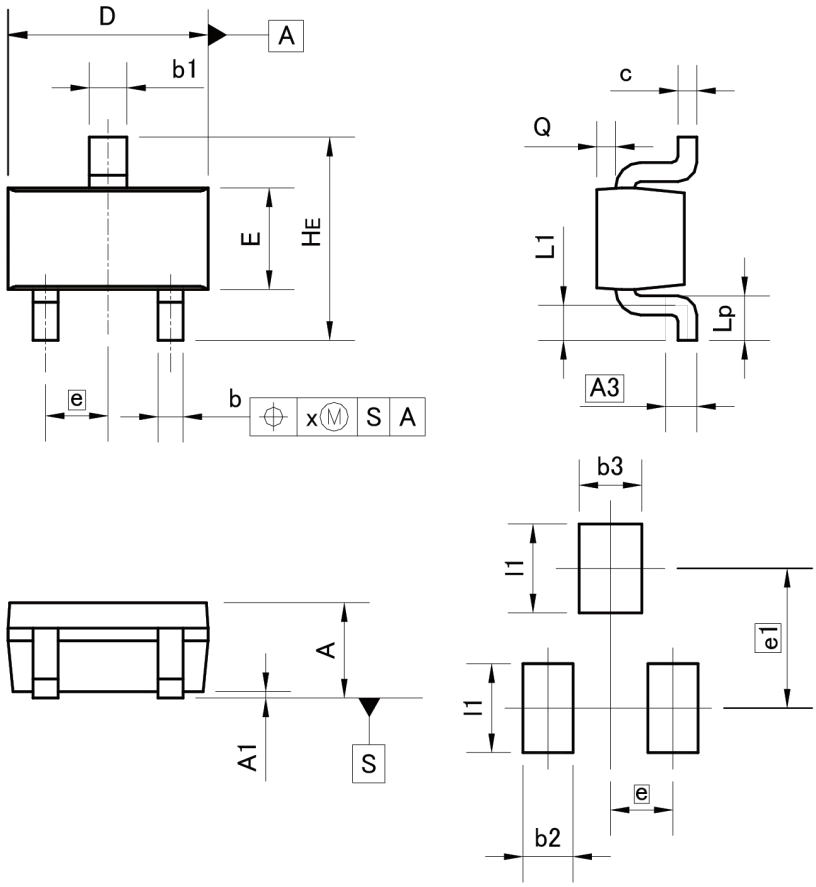
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.65	0.85	0.026	0.033
A1	0.00	0.10	0.000	0.004
A2	0.60	0.80	0.024	0.031
b	0.21	0.36	0.008	0.014
c	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	0.76	0.96	0.030	0.038
e	0.50		0.020	
HE	1.50	1.70	0.059	0.067
L	0.37		0.015	
Lp	0.35	0.55	0.014	0.022
x	−	0.10	−	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	−	0.46	−	0.018
e1	−	1.05	−	0.041
l1	−	0.65	−	0.026

Dimension in mm/inches

●Dimensions

EMT3



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

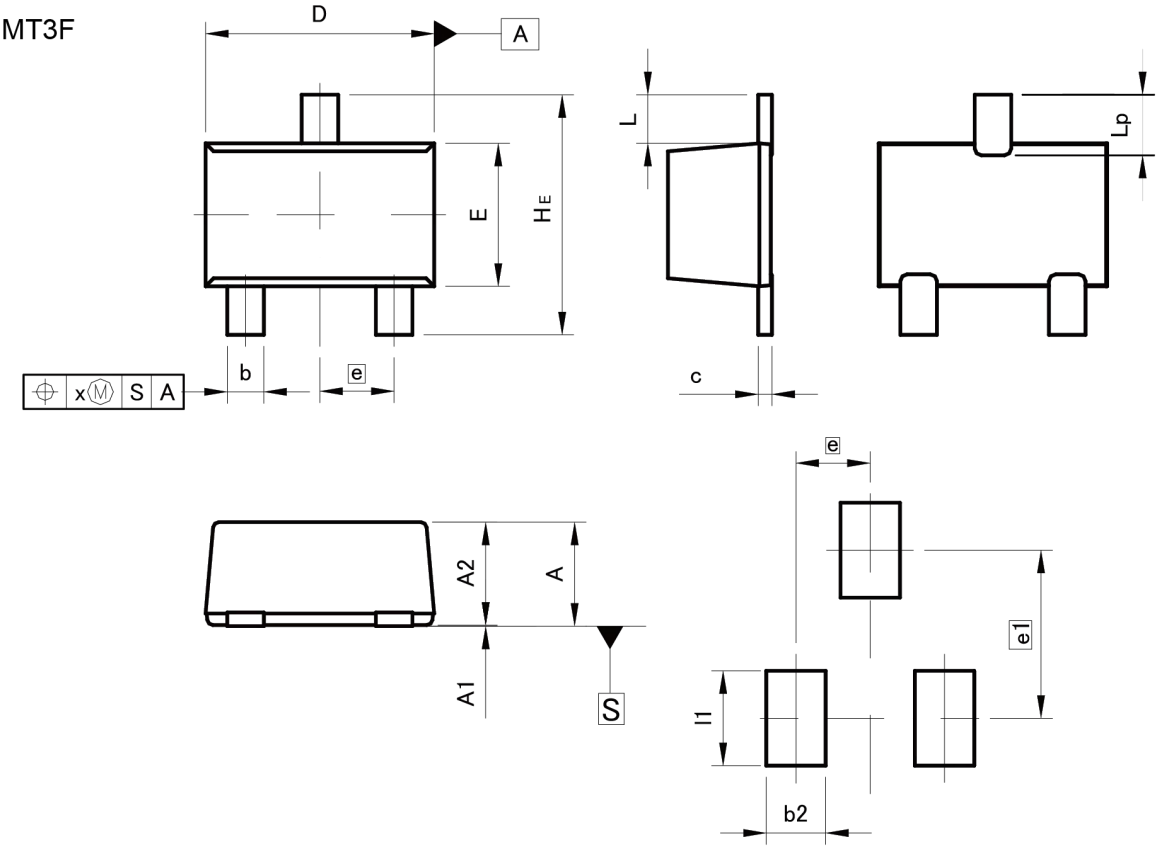
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.60	0.80	0.024	0.031
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.15	0.30	0.006	0.012
b1	0.25	0.40	0.010	0.016
c	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.70	0.90	0.028	0.035
e	0.50		0.020	
HE	1.40	1.80	0.055	0.071
L1	0.10	–	0.004	–
Lp	0.15	–	0.006	–
Q	0.05	0.25	0.002	0.010
x	–	0.10	–	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	–	0.40	–	0.016
b3	–	0.50	–	0.020
e1	1.10		0.043	
l1	–	0.70	–	0.028

Dimension in mm/inches

●Dimensions

UMT3F



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

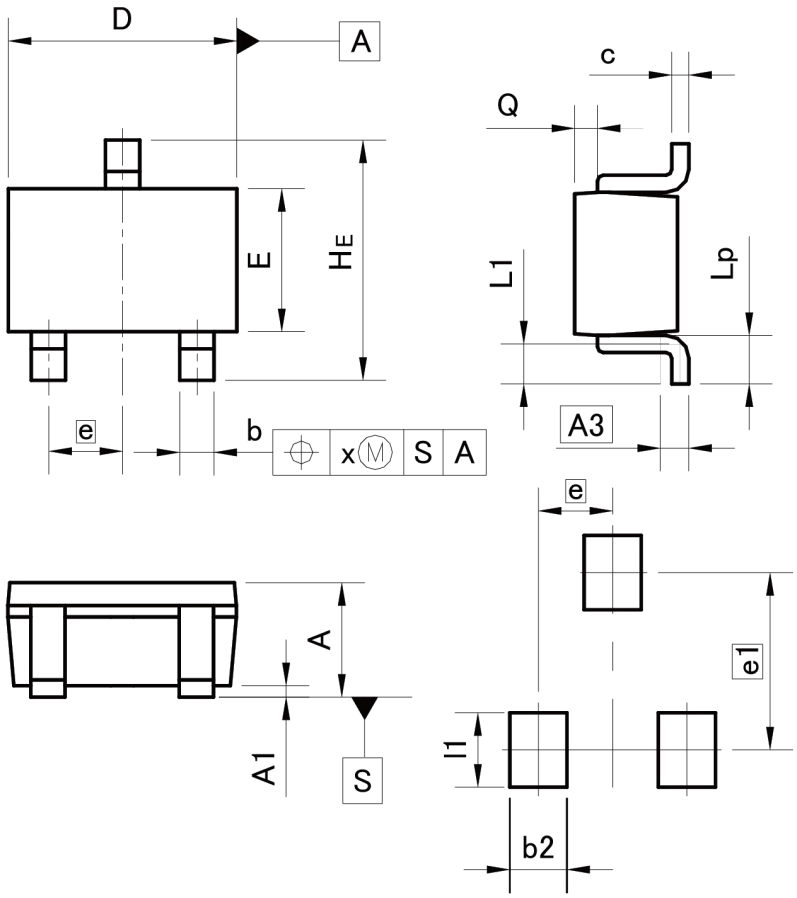
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.85	1.05	0.033	0.041
A1	0.00	0.10	0.000	0.004
A2	0.80	1.00	0.031	0.039
b	0.27	0.42	0.011	0.017
c	0.08	0.18	0.003	0.007
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
e	0.65		0.026	
HE	2.00	2.20	0.079	0.087
L	0.43		0.017	
Lp	0.43	0.63	0.017	0.025
x	–	0.10	–	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	–	0.52	–	0.020
e1	1.47		0.058	
l1	–	0.83	–	0.033

Dimension in mm/inches

●Dimensions

UMT3



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

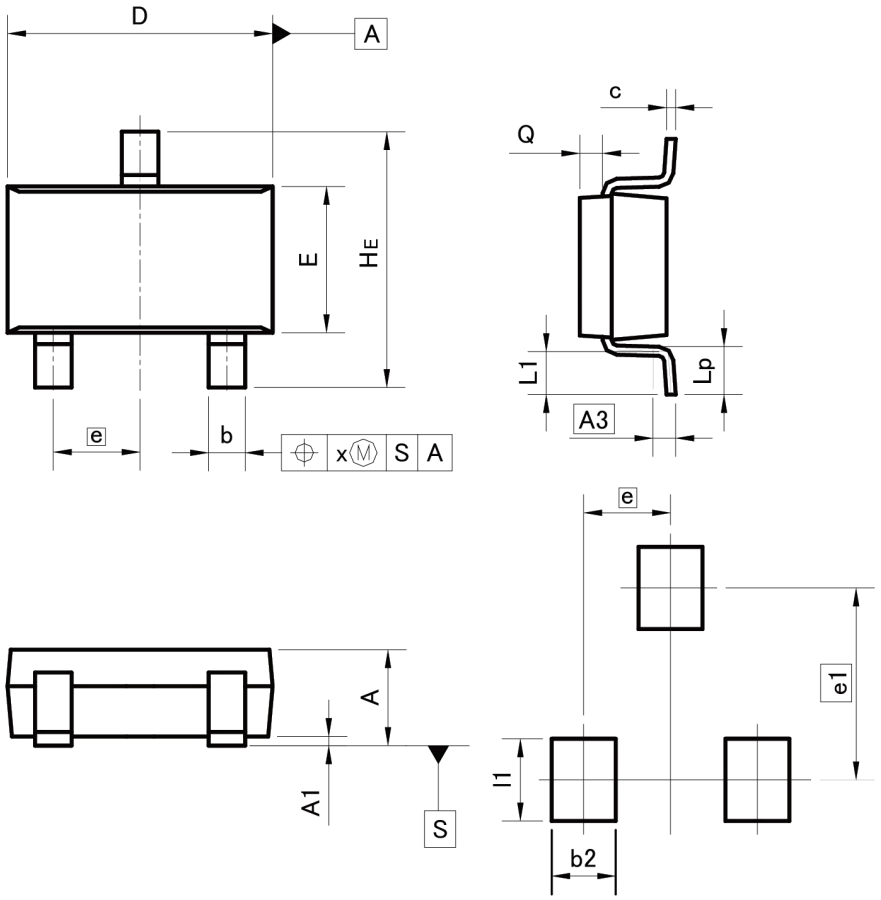
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.15	0.30	0.006	0.012
c	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
e	0.65		0.026	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
x	–	0.10	–	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	–	0.50	–	0.020
e1	1.55		0.061	
l1	–	0.65	–	0.026

Dimension in mm/inches

●Dimensions

SMT3



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.00	1.30	0.039	0.051
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.35	0.50	0.014	0.020
c	0.09	0.25	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
e	0.95		0.037	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
x	–	0.10	–	0.004
y	–	0.10	–	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	–	0.60	–	0.024
e1	2.10		0.083	
l1	–	0.90	–	0.035

Dimension in mm/inches

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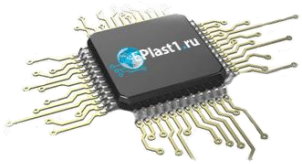
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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